



Schottky Diodes



- High frequency operation
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Guard ring for enhanced ruggedness and long term reliability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260°C

Typical Applications

Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

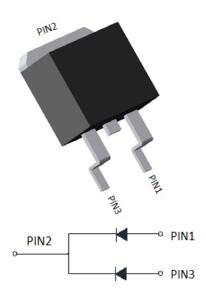
Mechanical Data

• Package: TO-263

Molding compound meets UL 94 V-0 flammability rating, RoHS-compliant

 Terminals: Tin plated leads, solderable per J-STD-002 and JESD22-B102

• Polarity: As marked



■Maximum Ratings (Ta=25°C Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	MBRBL3060CT
Device marking code			MBRBL3060CT
Repetitive Peak Reverse Voltage	VRRM	٧	60
Average Rectified Output Current @60Hz sine wave, R-load, T_a =25 $^{\circ}$ C	Ю	Α	30
Surge(Non-repetitive)Forward Current @60H _Z half sine-wave, 1 cycle, T _a =25°C	IFSM	Α	200
Current Squared Time @1ms≤t<8.3ms Tj=25°C,	I ² t	A ² s	167
Storage Temperature	T _{stg}	$^{\circ}$	-55 ~ +150
Junction Temperature	Tj	$^{\circ}$	-55 ~ + 150

■Electrical Characteristics (Ta=25°C Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	TEST CONDITIONS	MBRBL3060CT
Maximum instantaneous forward voltage drop per diode	VFM	>	IFM=15.0A	0.6
Maximum DC reverse current at rated DC blocking voltage per diode	IRRM1	mA	VRM=VRRM T _a =25°C	0.2
	IRRM2		VRM=VRRM T _a =100°C	30

MBRBL3060CT

■Thermal Characteristics (T_a=25°C Unless otherwise specified)

PARA	AMETER	SYMBOL	UNIT	MBRBL3060CT
Thermal Resistance	Between junction and case	Rө _{J-С}	°CMV	2.0

■Ordering Information (Example)

PREFERED P/N	UNIT WEIGHT(g)	MINIIMUM PACKAGE(pcs)	INNER BOX QUANTITY(pcs)	OUTER CARTON QUANTITY(pcs)	DELIVERY MODE
MBRBL3060CT	Approximate 1.43	50	2000	8000	Tube
MBRBL3060CT	Approximate 1.43	1000	2000	10000	Reel

■Characteristics (Typical)

FIG1:lo -Tc Curve

35.0
30.0
25.0
10.0
15.0
10.0
5.0
Case Temperature (°C)

FIG2:Surge Forward Current Capability

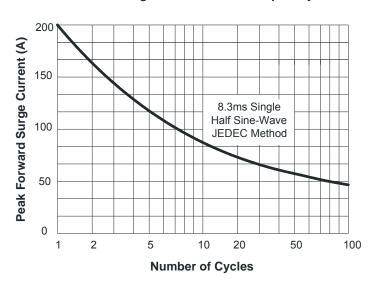


FIG3: Forward Voltage

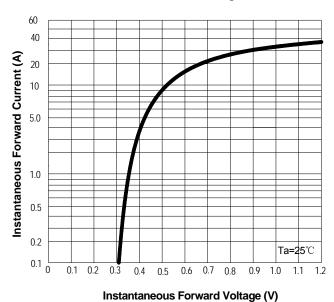
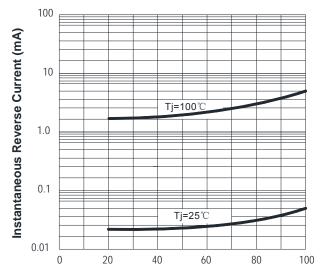


FIG.4: Typical Reverse Characteristics

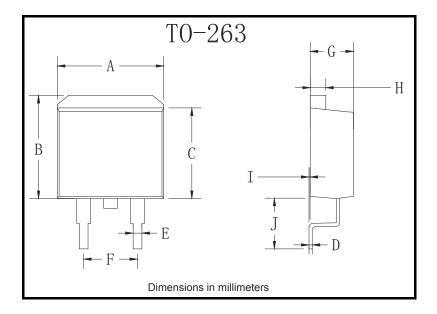


Percent of Rated Peak Reverse Voltage (%)



MBRBL3060CT

■Outline Dimensions



TO-263				
Dim	Min	Max		
Α	9.5	11.5		
В	9.7	10.5		
С	8.4	9.0		
D	0.28	0.64		
Е	0.68	0.94		
F	4.55	5.6		
G	4.04	5.10		
Н	1.14	1.4		
I	0	0.2		
J	4.9	6.05		

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